

# 37V Step-Up LED Driver with PWM to Constant Current Dimming Mode

#### **Features**

- Drive up to 10 serial LEDs
- PWM to Constant Current dimming mode
- Integrated 40V high current switch (1.3A limit)
- Wide V<sub>IN</sub> Input Range: 2.7V~5.5V
- Dimming scheme up to 100:1 range
- Up to 86% PWM converter Efficiency
- Low 200mV feedback voltage
- LED open-circuit (OVP) protection: 37V
- High switching frequency: 1.1MHz
- For Compact Solution Size
- Integrated Soft start
- < 1µA shutdown current</li>
- Compact SOT23-6, TSOT23-6, DFN2\*2-6
   Package
- Green compliant
- -40 to 85 °C Temperature range

### **Applications**

- LED backlighting
- Mobile Phones
- Handheld Devices
- Digital Photo Frames
- Automotive Navigation

### **Descriptions**

DIO5661 is a serial white LED driver, featuring an architecture of 86% high-efficiency current mode boost converter, driving up to 10 serial LEDs or a 3x13(3LEDs in rows) LED matrix. And it adopts PWM to Constant Current dimming control mode, with wide frequency range from 200Hz to 200kHz (The dimming frequency above 10kHz is recommended). The serial configuration assures the very most brightness consistency of the whole LED array.

DIO5661 works on 1.1MHz switching frequency, which can maximize current output of 1.3A limit and achieve high current conversion efficiency and result in external compact component size. Additionally, the total external component number is minimized due to the integrated low-side power MOSFET.

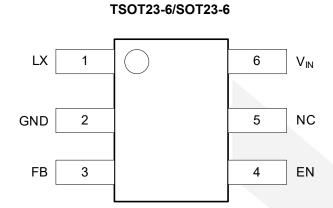
DIO5661 integrates multiple protection features, such as LED open-circuit protection, thermal shutdown protection and cycle-by-cycle input current limit protection. And the built-in soft start circuit limits inrush current when the circuit starts.

### **Ordering Information**

Order Part Number	Top Marking		TA	Package	
DIO5661ST6	61YW	Green	-40 to 85°C	SOT23-6	Tape & Reel, 3000
DIO5661TST6	61YW	Green	-40 to 85°C	TSOT23-6	Tape & Reel, 3000
DIO5661CD6	D61	Green	-40 to 85°C	DFN2*2-6 E	Tape & Reel, 3000



# Pin Assignment



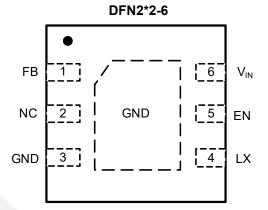


Figure 1 Top View

# **Pin Descriptions**

Name	Description
LX	Converter switching node
GND	Converter/IC ground
FB	Output feedback pin regulated at 0.2V
EN	IC enable and PWM dimming control pin
NC	No connected
V <sub>IN</sub>	IC supply voltage



# **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability.

Parameter		Rating	Unit	
Supply Voltage / V <sub>IN</sub>		-0.3 to 6.0	V	
High Voltage Nodes / LX			-0.3 to 40	V
Other pins / FB, EN			-0.3 to V <sub>IN</sub> + 0.3	V
Operating Temperature Ra	ange / T <sub>J</sub>		-40 to 150	°C
Storage Temperature Range / T <sub>S</sub>		-65 to 150	°C	
Lead Temperature Range / T <sub>LEAD</sub>		300	°C	
Thermal Resistance / θ <sub>JA</sub> DFN2*2-6		190	°C/M	
		DFN2*2-6	140	°C/W
Maximum Power Dissipation at T <sub>A</sub> <25°C		0.526	W	
		DEC: JESD22-A114	4	kV
ESD	CDM, JEI	DEC: JESD22-C101	2	kV

## **Recommend Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Rating	Unit
Supply Voltage	2.7 to 5.5	V
Operating Temperature Range	-40 to 85	°C



# **Electrical Characteristics**

Typical value: Vcc=3.6V,  $T_A=25^{\circ}C$ , unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
IC Supply						•
V <sub>IN</sub>	Input operating range		2.7		5.5	V
UVLO <sub>HYST</sub>	UVLO hysteresis			0.22		٧
	IC quiescent current(non switching)	FB=0.4V		0.22		mA
lα	IC quiescent current(switching)	FB=0V		0.67		mA
I <sub>SHDN</sub>	V <sub>IN</sub> pin shutdown current	EN=GND			0.1	μA
Boost Convert	er					
FB	FB pin accuracy		0.190	0.2	0.210	V
I <sub>FB</sub>	FB pin bias current			0.1		μA
R <sub>DS(ON)</sub>	NMOS on-resistance			0.4		Ω
I <sub>LX</sub>	LX pin leakage current			0.1		μA
I <sub>LIM</sub>	Peak NMOS current limit		1.0	1.3	1.6	Α
F <sub>SW</sub>	Oscillator frequency			1.1		MHz
D <sub>MAX</sub>	Maximum duty cycle			95		%
OVP	Over voltage threshold, Measured at V <sub>OUT</sub> pin			37	39	V
Ts	Start-up time			1		ms
Logic Signal						
V <sub>TH-L</sub>	Logic low threshold				0.4	V
V <sub>TH-H</sub>	Logic high threshold		1.4			V
T <sub>OFF</sub>	EN low to shutdown time			2		ms
F <sub>EN</sub>	Dimming frequency		0.2		200	kHz
_	IC junction thermal shutdown threshold			146		°C
T <sub>J-TH</sub>	IC junction thermal shutdown hysteresis			19		°C

Specifications subject to change without notice.



# **Application Circuit**

In typical application, DIO5661 is competent in the below two configurations: 10 series LED-Array and 3(row)x13 LED Matrix. As depicted in following figures:

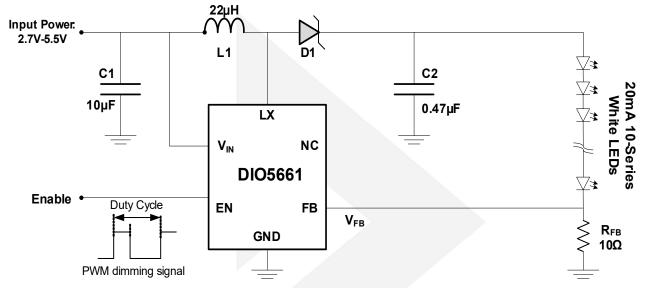


Figure 2. 10 Series LED Array Application Circuit Configuration

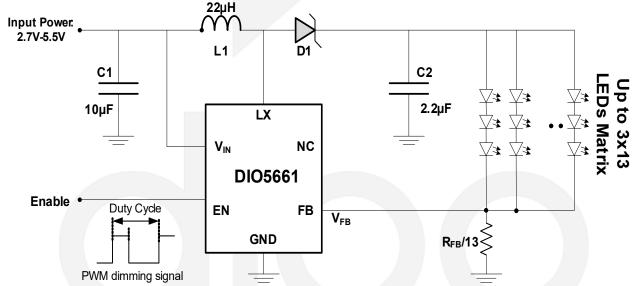


Figure 3. 3x13 (3 LEDs in row) LED Matrix Application Circuit Configuration

Note: A 22µH inductor is recommended for DIO5661.



# **Functional Block Diagraph**

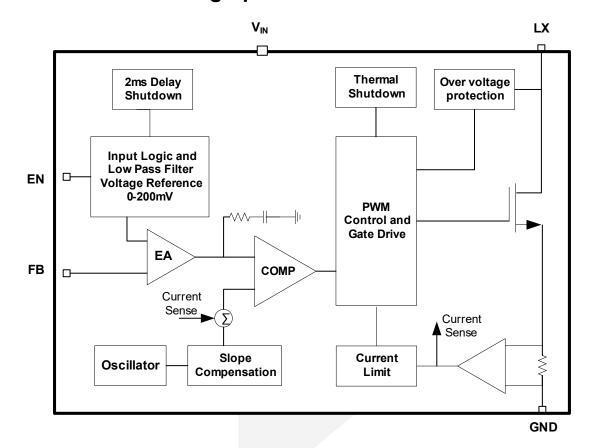


Figure 4. Functional Block Diagraph



### **Operation Principle**

DIO5661 utilizes a constant frequency current-mode boost converter architecture to power white LED strings or arrays by pumping current precisely regulated by feedback voltage V<sub>FB</sub> and feedback resistor R<sub>FB</sub>, illustrated in Figure 6, Page 8.

As illuminated in the Functional Block Diagraph above, PWM Control and Gate Drive Block periodically opens and closes the Power MOSFET synchronized with Oscillator. At the rising edge of Oscillator pulse, Power MOSFET is turned on, while closed when the comparator tells the Current Sense slope ramp goes above the output "difference" of error amplifier EA. The Current Sense slope ramp is generated by Current Sense from sampling inductor charging current and compensated by Slope Compensation. And the output "difference" comes from comparing feedback voltage V<sub>FB</sub> with internal reference voltage V<sub>REF</sub> by Error Amplifier EA. Both the two close loops assure the output current stabilization and make feedback voltage V<sub>FB</sub> in consistency with reference voltage V<sub>REF</sub>. and we will see in the next section that the IC dims LEDs by regulating the reference voltage.

DIO5661 integrates soft-start to limit the inrush current on the output. And DIO5661 also features internal protection circuits such as over-voltage protection (OVP), cycle-by-cycle current limit protection and thermal shutdown.

DIO5661 adopts PWM dimming control by regulating the reference voltage. The PWM signals through a low-pass filter, then transfer to an analog reference voltage. (PWM to Constant Current Mode). Pin EN listens PWM signals from 200Hz to 200kHz. Once powered on, the DIO5661 gradually soft starts to output LED current proportional to the PWM signal duty cycle. A 100% duty cycle PWM signal leads the IC to maximum current output. And a 0% duty cycle PWM signal or a 2ms long low pulse will shutdown the IC. Any non-0% duty cycle PWM signal to Pin EN will arouse the IC again. Dimming scheme up to 100:1 range.

All the dimming process could be explained in detail that, the output LED current is controlled by the internal feedback voltage  $V_{FB}$ , as illustrated in the following Application Notes- LED current Setting Section. And the value of  $V_{FB}$  (from 0 to 200mV) is absolutely proportional to the duty cycle of PWM signal (from 0% to 100%). More is depicted in the below figure.

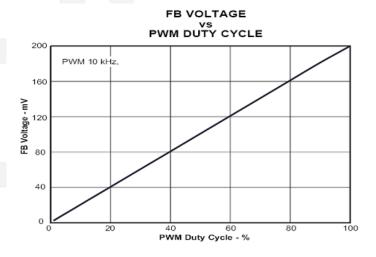


Figure 5. Duty cycle of PWM signal vs. Reference Voltage VREF



## **Application Notes:**

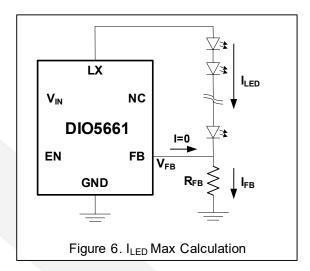
#### **MAX LED Current Settings**

LED Current is determined by the current through the feedback resistor  $R_{FB}$ , as depicted in the right-hand figure.  $V_{FB}$  is a high-impedance state input feedback voltage, so no current goes through Pin FB and the built-in "boost" DC/DC has to pump current to feed  $I_{FB}$ .

 $V_{\text{FB}}$  equals to  $V_{\text{REF}}$  which is internally set to a maximum value of 200mV. So

 $I_{LED(MAX)} = 200 \text{mV} / R_{FB}$ 

For LED current accuracy, 1% precision resistor is recommended.



#### Feedback Voltage VFB Calculation

The feedback voltage  $V_{FB}$  is regulated by the internal reference voltage  $V_{REF}$ , which is in detail described in Figure 5. So the  $V_{FB}$  is approximately same as  $V_{REF}$  in the timing, except for that  $V_{FB}$  always has a delay with respect to  $V_{REF}$  since both in the start-up or the dimming process, the system takes time to adjust  $V_{FB}$  equal to  $V_{REF}$ . if we neglect these delays,  $V_{FB}$  changes with Pin EN signal just as the  $V_{REF}$ .

#### Recommended LED Dimming Method for 10-LEDs series Application

EN pin PWM signal dimming

The principle of PWM dimming control is explained in detail above. A certain duty cycle PWM signal to EN pin will reset the reference voltage  $V_{REF}$ , which will in turn determine the LED current. If we set  $R_{FB} = 10.0\Omega$ , so  $I_{LED(MAX)} = 20 \text{mA}$ , then we have  $I_{LED}$  changes with the PWM duty cycle as the following:

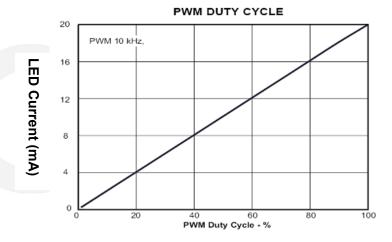


Figure 7. Duty cycle of PWM signal vs. LED Current



#### Inductor Selection

A  $10\mu\text{H}\sim22\mu\text{H}$  inductor is recommended for both 10-LED serial string and 3x13 LED matrix application. A low DCR inductor could be suggested if a high efficiency is critical. The inductor's saturation current rating should also exceed the peak input current, especially for high load current application such as 3x13 matrix.

Table 1. Inductor Selector

Part Number	Inductor(µH) @100KHz,1V	DCR(Ω) +/-30%	Min. Self-resonant Frequency(MHz)	Saturation Current(A)	Heat Rating Current(A)
SWPA8040S100MT	10+/-20%	0.029	15	3.60	3.30
SWPA8040S220MT	22+/-20%	0.069	9.5	2.40	2.10

The Calculation Forluma of Inductor Peak to Peak (Ipp):

$$I_{PP} = \frac{Vin \times D}{L \times Fs}$$

The Calculation Forluma of The Cycle Duty:

$$D = \frac{ton}{Ts} = \frac{Vout + Vf - Vin}{Vout + Vf}$$

Vin : The voltage of Input
Ipp : Inductor Peak to Peak
L : The Inductor Value

Vf: The forward bias voltage of Schottky diode

Fs: Switching frequency (1/Ts)

Vout: The voltage of Output

The Calculation Forluma of The Inductor Peak current:

$$Ipeak = lin + \frac{Ipp}{2} + \frac{Vout * Iout}{Vin * \eta} + \frac{Vin \times D}{2 \times L \times Fs}$$

#### **Capacitor Selection**

Small size ceramic capacitors are recommended for DIO5661 application. A 10µF input capacitor and a 0.47µF output capacitor are recommended for 10/8/6-Series LED applications. Larger value output capacitors like 2.2µF are recommended in higher output current applications to minimize output ripple. Ceramic capacitor Vendors such as Murata, AVX, Taiyo Yuden are recommended.

#### **Diode Selection**

Since DIO5661's low forward voltage drop and fast reverse recovery time, a schottky diode is recommended. The current rating of the schottky diode should exceed the peak current of the boost converter. The voltage rating should also exceed the target output voltage.



#### Table 2. Diode Selector

Applications	Schottky Diode Part Number	Forward Voltage/ V	Forward Current mA	Reverse Voltage V	Manufacturer
20mA, 8/10 Serial LEDs 37V OVP	PMEG6010CEJ	0.57	1000	60	NXP

#### **PCB Layout Design Recommendation**

As for all switching power supplies, especially those high frequency and high current ones, layout is an important design step. If layout is not carefully done, the regulator could suffer from instability as well as noise problems. To reduce switching losses, the LX pin rise and fall times are made as short as possible. To prevent radiation of high frequency resonance problems, proper layout of the high frequency switching path is essential. Minimize the length and area of all traces connected to the LX pin and always use a ground plane under the switching regulator to minimize inter-plane coupling. The loop including the PWM switch, Schottky diode, and output capacitor, contains high current rising and falling in nanosecond and should be kept as short as possible. The input capacitor needs not only to be close to the V<sub>IN</sub> pin, but also to the GND pi in order to reduce the IC supply ripple. Figure 8 shows a sample layout.

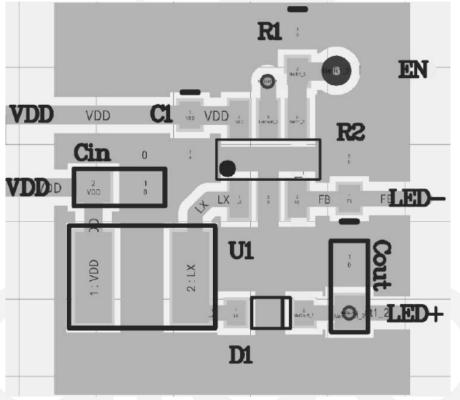
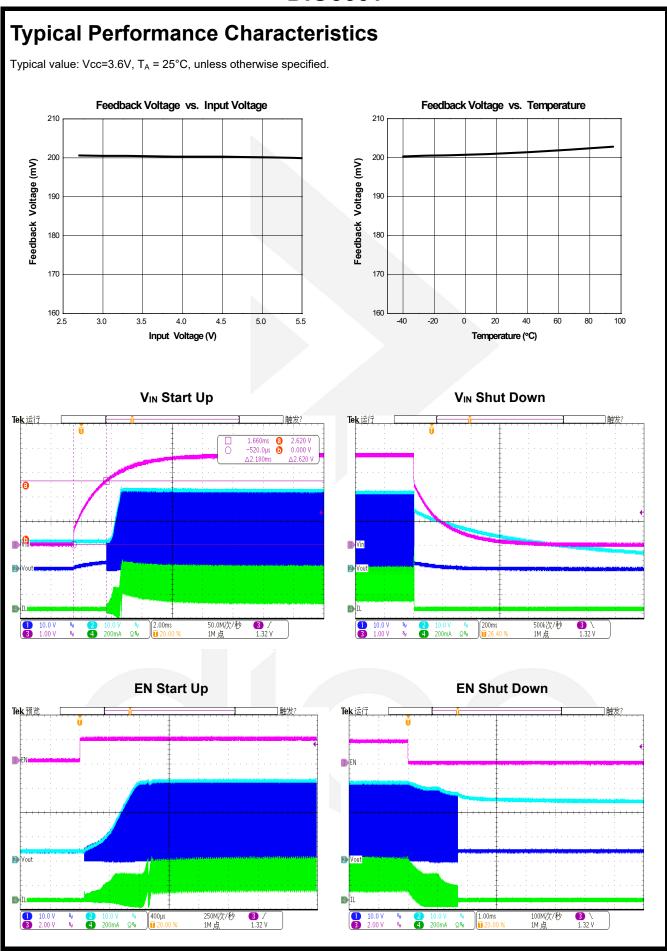
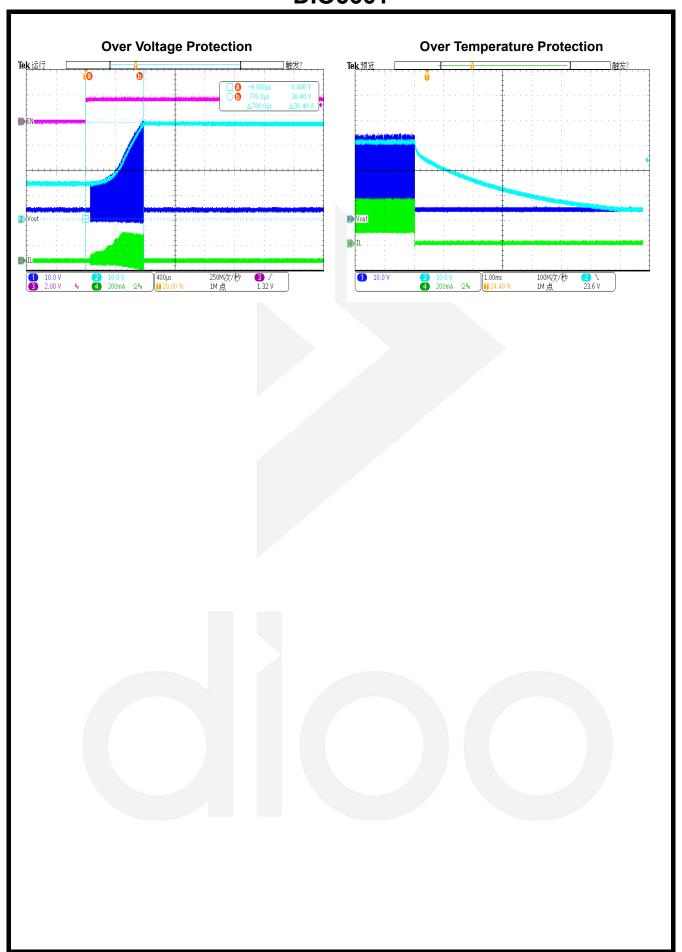


Figure 8. PCB Layout recommended



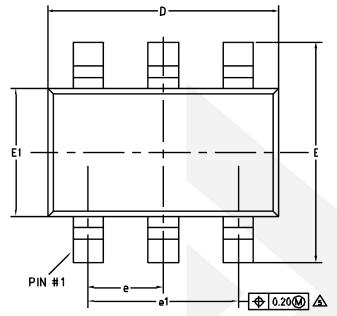


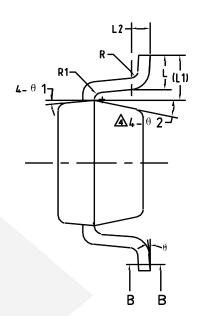


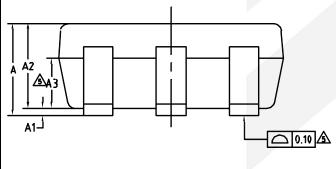


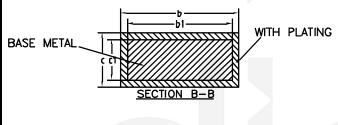








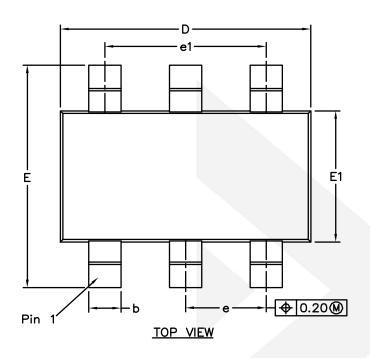


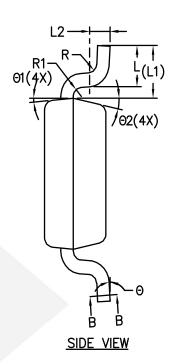


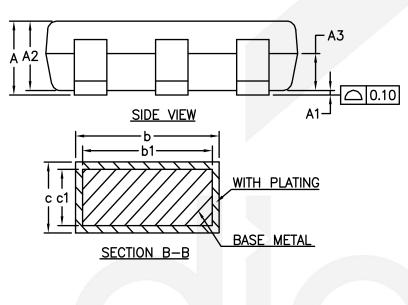
COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)				
Symbol	MIN	NOM	MAX	
Α	-	-	1.25	
A1	0	-	0.15	
A2	1.00	1.10	1.20	
A3	0.60	0.65	0.70	
b	0.36	ı	0.50	
b1	0.36	0.38	0.45	
С	0.14	-	0.20	
c1	0.14	0.15	0.16	
D	2.826	2.926	3.026	
Е	2.60	2.80	3.00	
E1	1.526	1.626	1.726	
е	0.90	0.95	1.00	
e1	1.80	1.90	2.00	
L	0.35	0.45	0.60	
L1		0.59REF		
L2		0.25BSC		
R	0.10	-	-	
R1	0.10	-	0.25	
Θ	0°	-	8°	
Θ1	3°	5°	7°	
Θ2	6°	-	14°	



# **Physical Dimensions: TSOT-23-6**



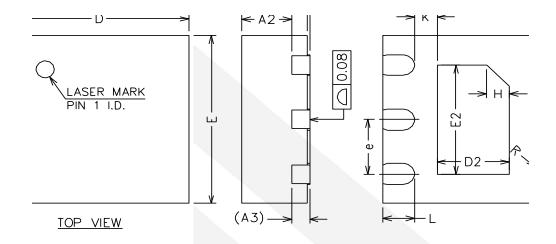


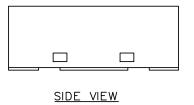


COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)				
MIN	МОМ	MAX		
-	-	0.90		
0	-	0.15		
0.65	0.75	0.85		
0.35	0.40	0.45		
0.36	-	0.50		
0.36	0.38	0.45		
0.14	-	0.20		
0.14	0.15	0.16		
2.85	2.95	3.05		
2.60	2.80	3.00		
1.60	1.65	1.70		
0.90	0.95	1.00		
1.80	1.90	2.00		
0.30	0.45	0.60		
	0.575REF			
	0.25BSC			
-	-	0.25		
-	-	0.25		
0°	-/	8°		
3°	5°	7°		
10°	12°	14°		
	0 0.65 0.35 0.36 0.14 0.14 2.85 2.60 1.60 0.90 1.80 0.30	MIN         NOM           -         -           0         -           0.65         0.75           0.35         0.40           0.36         -           0.36         0.38           0.14         -           0.14         0.15           2.85         2.95           2.60         2.80           1.60         1.65           0.90         0.95           1.80         1.90           0.30         0.45           0.25BSC         -           -         -           0°         -           3°         5°		



# Physical Dimensions: DFN2\*2-6 E





COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)				
Symbol	MIN	NOM	MAX	
Α	0.70	0.75	0.80	
A1	0	0.02	0.05	
A2	0.50	0.55	0.60	
A3		0.20REF		
b	0.20	0.25	0.30	
D	1.90	2.00	2.10	
E	1.90	2.00	2.10	
D2	0.70	0.80	0.90	
E2	1.20	1.30	1.40	
е	0.55	0.65	0.75	
Н		0.20REF		
K	0.20	-	-	
L	0.30	0.35	0.40	
R	0.11	-	- /-	



### **CONTACT US**

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